Electronic Structure and Charge Transfer in the TiO$_2$ Rutile (110)/Graphene Composite Using Hybrid DFT Calculations

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Abstract

Composite systems of TiO$_2$ with nanocarbon materials, such as graphene, graphene oxide and carbon nanotubes, have proven to be efficient photocatalyst materials. However, detailed understanding of their electronic structure and the mechanisms of the charge transfer processes is still lacking. Here, we use hybrid density functional theory calculations to analyse the electronic properties of the ideal rutile (110)-graphene interface, in order to understand experimentally observed trends in photoinduced charge transfer. We show that the potential energy surface of pristine graphene physisorbed above rutile (110) is relatively flat, enabling many possible positions of graphene above the rutile (110) surface. We verify that tensile and compressive strain has negligible effect on the electronic properties of graphene at low levels of strain. By analysing the band structure of this composite material and the composition of the valence and conduction band edges, we show that both the highest occupied states and the lowest unoccupied states of this composite are dominated by graphene, and that there is also a significant contribution of Ti orbitals to the two lowest unoccupied bands. We suggest that a transition from graphene-dominated occupied bands to mixed graphene and TiO$_2$-based unoccupied bands is responsible for the experimentally observed photoinduced charge transfer from graphene to TiO$_2$ under visible light irradiation; however, the most stable state for an excess (e.g. photoexcited) electron is localised on the carbon orbitals, which make up the lowest-energy conduction band. This separation of photogenerated electrons and holes makes TiO$_2$-graphene an efficient photocatalyst material.

Introduction

Heterogeneous photocatalysis is a subject area which has seen continuous progress over the years since the first proof-of-concept experiment by Fujishima and Honda. The potential for such materials to be used for solar energy conversion, through photocatalytic water splitting or CO$_2$ reduction, is of tremendous importance for supplementing (and subsequently
reducing) the use of limited chemical fuel sources such as oil and natural gas. Furthermore, the ability for these functional materials to clean air and water borne pollutants from industrial sources should not be overlooked as these present a further environmental concern.

Titanium dioxide (TiO$_2$) has been a popular material for heterogeneous photocatalysts in many forms due to its low cost, favourable band positions for water splitting, chemical stability, and versatility towards different forms of modification. It is abundantly clear, however, that single-component photocatalysts are insufficient for solar energy applications, as metal oxides generally suffer from poor photocatalytic performance under solar irradiation — emanating from a wide band gap (3.0–3.2 eV for TiO$_2$) and high charge carrier recombination rates.

Combination of TiO$_2$ with another semiconducting material in a heterojunction arrangement has been a long-studied concept in both photovoltaics and photocatalysis, and has been quite successful as a means of tackling both the charge recombination problem (through interfacial charge carrier separation) and, by using a narrow-gap semiconductor, enabled extending photon absorption into the visible region. A popular approach from previous decades has been to combine TiO$_2$ with cadmium sulphide (CdS) quantum dots. Anchoring CdS to the surface of TiO$_2$ has been shown to increase photocatalytic activity notably and longevity to some extent, however issues with photocorrosion in particular pose a problem for potential industrial applications.

More recently, studies have been focused on carbon-nanostructure/TiO$_2$ composite materials, starting with carbon nanotubes (NTs) following their isolation in the early 1990s. Following a novel synthesis technique by Williams et al., there has been a surge in interest in composites of TiO$_2$ with graphene. Originally it was proposed that the large surface areas and electrical conductivities of these carbon nanostructures should help efficiently separate generated charge carriers, thus enhancing photocatalytic efficiency. Numerous experimental studies have demonstrated that the addition of graphene and carbon nanotubes to TiO$_2$ also extends the photon absorption spectrum of
the material into the visible region.

Such studies provide evidence for strong electronic interaction between the two systems, however, despite attempts to study the mechanism\cite{31,38,39} the nature of this charge transfer across the interface is still not fully understood. In particular, the early experiments demonstrated that photoinduced electrons are transferred from TiO$_2$ to graphene,\cite{29} so that graphene is expected to behave as an electron shuttle.\cite{40} Shortly thereafter, photocurrent measurements together with theoretical calculations showed that enhanced light absorption originates from charge-transfer excitation from graphene to TiO$_2$, in the direction opposite to what previously observed.\cite{41} Moreover, several experimental studies showed that charge transfer in both directions is possible (see the overview in Table 1), in particular, dependence of charge transfer direction on the excitation wavelength was demonstrated: from TiO$_2$ to graphene when excited by UV light, and from graphene to TiO$_2$ when excited by visible light.\cite{38,39}

Computational studies of TiO$_2$-nanocarbon interfaces have made significant steps in understanding the nature of charge transfer. Notably, it has been demonstrated that there is strong electronic overlap and large interfacial binding energy across the physisorbed TiO$_2$ rutile (110)-graphene interface.\cite{41} Ground-state charge transfer from graphene to TiO$_2$ has been demonstrated, as well as photoinduced charge transfer from graphene to TiO$_2$.\cite{41} Time-dependent density functional theory (TD-DFT) and non-adiabatic molecular dynamics (NAMD) studies by Long and Prezhdo,\cite{43} in addition to transient UV/Vis absorption spectroscopy measurements by Manga et al.,\cite{42} have shown that transfer of photoexcited electron from graphene to TiO$_2$ is efficient and is faster than the average excited state lifetime for graphene — with measured electron transfer timescales of 200–250 femtoseconds.\cite{42} These studies have shown that graphene can act in this composite system as a visible/near infrared photon absorber (photosensitiser) and as a means of providing charge carrier separation, while the direction of charge transfer depends on the relative positions of electronic bands on each side of the interface.
Table 1: Overview of several experimental and computational investigations of photoinduced charge transfer in TiO$_2$-graphene systems

<table>
<thead>
<tr>
<th>Research Article</th>
<th>System Studied</th>
<th>Methodology</th>
<th>Observed Direction of Charge Transfer</th>
</tr>
</thead>
<tbody>
<tr>
<td><strong>Experimental</strong></td>
<td></td>
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<tr>
<td>Manga et al. 2009$^{[42]}$</td>
<td>TiO$_2$/Graphene Oxide</td>
<td>Femtosecond transient UV absorption spectroscopy</td>
<td>Graphene to TiO$_2$</td>
</tr>
<tr>
<td>Liang et al. 2012$^{[39]}$</td>
<td>TiO$_2$/Graphene</td>
<td>UV-Visible photoluminescence quenching</td>
<td>Both directions possible</td>
</tr>
<tr>
<td>Pastrana-Martínez et al. 2012$^{[38]}$</td>
<td>TiO$_2$/Reduced Graphene Oxide</td>
<td>UV-Visible photocatalysis kinetics</td>
<td>Graphene to TiO$_2$ (Visible Light); TiO$_2$ to Graphene (UV Light)</td>
</tr>
<tr>
<td>Xu and Yang 2013$^{[31]}$</td>
<td>ZnO/Reduced Graphene Oxide</td>
<td>Visible-region photocatalysis kinetics</td>
<td>Graphene to ZnO</td>
</tr>
<tr>
<td><strong>Theoretical</strong></td>
<td></td>
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<tr>
<td>Du et al. 2011$^{[41]}$</td>
<td>Rutile (110)/Graphene</td>
<td>LDA + U, electron/hole density plots, simulation of optical absorption</td>
<td>Graphene to Rutile</td>
</tr>
<tr>
<td>Long et al. 2012$^{[43]}$</td>
<td>Rutile (110)/Graphene</td>
<td>PBE + U, time-dependent DFT, non-adiabatic molecular dynamics</td>
<td>Graphene to Rutile</td>
</tr>
<tr>
<td>Li et al. 2013$^{[44]}$</td>
<td>Anatase (101)/Graphene</td>
<td>PBE + U, electron density difference, density of states</td>
<td>Graphene to Anatase</td>
</tr>
<tr>
<td>Masuda et al. 2014$^{[45]}$</td>
<td>Anatase (001)/Graphene</td>
<td>PBE + U, Bader charge analysis, electron density plots</td>
<td>Graphene to Anatase</td>
</tr>
</tbody>
</table>

These key studies were followed by a number of further studies of the interfaces of graphene with rutile$^{[46]}$ and anatase$^{[47,48]}$ polymorphs of TiO$_2$ and other oxides, such as CeO$_2$$^{[49]}$ and SrTiO$_3$$^{[50]}$ as well as several studies of small TiO$_2$ clusters on graphene$^{[47,48]}$ and graphene-like flakes on TiO$_2$ surfaces$^{[51,52]}$ and larger TiO$_2$/graphene/dye heterostructures$^{[53,54]}$. Notably, several of these works confirm the role of graphene as photosensitiser, leading to photoinduced charge transfer from graphene to TiO$_2$,$^{[44,50]}$ similar to the first computational studies$^{[41,43]}$ and in agreement with experiments.$^{[55,56]}$ However, no computational studies have investigated the alternative process, photoinduced charge transfer from TiO$_2$ to graphene. This work aims to investigate the origins of the two experimentally observed directions of photoinduced charge transfer.
Studying the interface itself is, from a purely computational perspective, very challenging. First, the crystal structures of TiO$_2$ and graphene differ in size and shape. To generate the composite unit cell (UC), each component system needs to be extended such that the resulting composite supercells are commensurate. The resulting composite unit cells are typically very large (in the range of 100-300 atoms) and computationally demanding to simulate and require efficiently-scaling parallel software. Second, known shortcomings with pure DFT functionals are the underestimation of semiconductor band gaps and the tendency to inaccurately delocalise the electron density. To better represent the electronic properties of TiO$_2$, hybrid DFT/Hartree-Fock (HF) functionals can be used in the simulations, but with large systems such as those represented here the computational cost (typically depending on the number of basis functions $n$ as $n^4$) is high. Finally, the system also contains semi-metallic graphene, which can make hybrid DFT simulations more susceptible to problems with numerical stability and requires careful selection of convergence parameters in the calculations (see the Computational Methodology section).

The complexity and the high computational expense of studying this interface practically limit the choice of the methods available for use. In particular, for this system it has been common for studies to employ pure DFT with a Hubbard ‘U’ correction, which can correctly reproduce the band gaps and band positions of TiO$_2$, but where the choice of the parameter $U$ can be quite ambiguous (values ranging from 4.0 to 5.5 eV, and even as high as 9.0 eV have been used in studies of TiO$_2$-graphene interfaces). Hybrid functionals would be a more reliable choice, which allow consistent comparison of TiO$_2$-based systems. However, to the best of our knowledge, only one group recently used hybrid DFT functionals to study a TiO$_2$ anatase (101)/graphene interface. Even higher accuracy in describing the electronic structure of this system could, in principle, be achieved using many-body perturbation theory (such as the GW approximation used for bulk TiO$_2$ in Ref.), but such calculations would be prohibitively expensive.

The aim of this study is to investigate the nature of a model rutile (110)/graphene inter-
face using high-accuracy hybrid DFT calculations, in particular focussing on the electronic structure and the nature of electron transfer in this system. To do this, we choose a range-separated screened-exchange HSE06 functional,\textsuperscript{70,71} which gives accurate values of band gaps and defect states in TiO$_2$ and other transition metal oxides.\textsuperscript{66,72} To mitigate the difficulty of optimisation of large composite cells, we use a two-step procedure and perform optimisation using very efficient CP2K software\textsuperscript{73} at the $\Gamma$ $k$-point, followed by high-accuracy calculations of the electronic structure at a dense $k$-point grid using CRYSAL14 software.\textsuperscript{74}

The manuscript is organised as follows. After outlining the computational methods used, we discuss the construction of the composite rutile (110)-graphene cell. Then, we explore the effect of strain (arising from lattice mismatch) on the electronic properties of graphene. After that, we explore the structure and interaction of the rutile (110)-graphene interface, followed by the analysis of the electronic structure of this interface. Finally, these properties are summarised and the charge transfer capabilities are discussed in the context of this work and the wider literature.

**Computational Methodology**

**Computational Methods**

All geometry optimisations and binding energy analyses were carried out using the QUICK-STEP program,\textsuperscript{73} within the CP2K software package. All pure DFT calculations used the PBE\textsuperscript{75} exchange-correlation functional, with empirical Grimme D2\textsuperscript{76} dispersion correction included. The calculations utilised Goedecker-Teter-Hutter pseudopotentials\textsuperscript{77} and double-zeta basis sets with diffuse and polarisation functions, which have been optimised for use in CP2K.\textsuperscript{78} The vacuum space between graphene and the bottom of the periodic image of the TiO$_2$ slab was 19.5 Å. All atom positions were fully relaxed, similar to the previous studies of TiO$_2$\textsuperscript{79-82} and TiO$_2$/graphene interfaces.\textsuperscript{45,47} An alternative would be to fix the lowest layer of TiO$_2$ and saturate the dangling bonds with pseudo-hydrogen atoms, as done
e.g. in Ref. to avoid changes in the electronic structure due to fixed undercoordinated atoms. Basis set superposition error (BSSE) in calculations of binding energies was corrected using the counterpoise method. For all hybrid DFT calculations the HSE06 range-separated exchange-correlation functional was used, in addition to the Auxiliary Density Matrix Method (ADMM), featured in the CP2K software package. In such calculations Hartree-Fock exchange is computed with a much smaller auxiliary basis set, while the primary basis set (carried over from PBE-level calculations in this instance) is used in the non-HF exchange part of the functional. The auxiliary basis set cpFIT3 (contracted, 3 gaussian exponents per valence orbital, includes polarisation d-functions) was used for carbon and oxygen, while FIT11 (4 s, 3 p, and 3 d shells and 1 f shell in total) was used for titanium. An example of the input file with the settings used in this study is provided in the Supporting Information (SI).

The optimised coordinates obtained in CP2K HSE06 calculations were then used as input for calculations with a fine k-point grid using the CRystal14 software package. All density of states, band structure, and graphene strain test calculations were carried out using CRystal14. For calculations of properties of the rutile (110)/graphene interface a Monkhorst-Pack k-point mesh of $12 \times 12 \times 1$ was used. For the graphene strain tests a denser k-point mesh of $16 \times 16 \times 1$ was used. Band structures of graphene were calculated with 1800 points along the path, and band structures of the TiO$_2$/graphene composite with 300 points along the path. The DFT functional used for graphene strain tests was PBE (in line with the recent computational studies of graphene), and the hybrid DFT functional used for TiO$_2$-graphene calculations was HSE06. Empirical Grimme D2 dispersion corrections were added in all CRystal14 calculations. All these calculations used all-electron triple-zeta basis sets with polarisation functions from the work of M. Peintinger et al. The height of the cell was formally set to 500 Å (no periodicity in the z direction in the 2D slab model in CRystal). In order to obtain band energies relative to the vacuum level, the electrostatic potential of the vacuum region above the unit cell was calculated and was then subtracted.
from each band energy.

Unit Cell Construction

To construct the unit cell of the rutile (110)/graphene composite, the lowest common multiples of the cell parameters of rutile (110) compared to graphene need to be found. The rutile (110) unit cell has a rectangular shape (see Figure 1), with cell parameters $A = 6.529$ Å and $B = 2.995$ Å (obtained from our CP2K PBE calculations of bulk rutile, see SI Section S1 for details). Graphene was represented with an orthorhombic unit cell for ease of fitting with rutile (110) (see Figure 1), with the lattice parameters defined from the experimental value of the graphene carbon-carbon bond length (1.42 Å).

Rutile (110)/Graphene System Construction

![Composite Unit Cell Diagram]

Figure 1: Construction of the composite rutile (110)/graphene unit cell used in this research.

It was found that the best compromise of system size with commensurability was to fit a $3 \times 6$ (armchair × zigzag) supercell of graphene with a $2 \times 5$ supercell of rutile (110), where the armchair line of graphene runs parallel to the $A$ lattice vector of rutile (110) (Figure 1). This composite UC results in an applied strain to graphene of +2.27% and +1.44% in the armchair and zigzag lines, respectively. This is the same size of the composite unit cell as
was used a previous DFT+U study of the rutile (110)-graphene interface. This smallest commensurate unit cell, if used with a thin 6 atomic layer rutile (110) slab (two unit-cell layers), has a total of 192 atoms (40 TiO$_2$ units and 72 carbon atoms); the 9 atomic layer (three unit-cell layers) rutile (110) slab results in a 252-atom cell; both were used in this work.

An alternative UC of the composite was also considered, where the zigzag line of graphene runs parallel to the A cell vector of rutile (110). Here the smallest identified commensurate unit cell ("commensurate" defined here as having mismatch under 5%) comprised of an 8 × 5 supercell of graphene with a 3 × 7 supercell of rutile (110), this resulted in an applied compressive strain of -1.43% and -0.47% to the armchair and zigzag graphene directions, respectively. This composite UC, containing a total of 412 atoms with a 6 atomic layer slab of rutile (110), was constructed to investigate the effect of orientation of graphene relative to rutile (110) on the physical properties of the interface. The structure (interfacial C-O distances) and interfacial interaction energies (described in the next section) were very similar to the smaller cell described above and in Figure 1, therefore this larger cell was not investigated further.

Larger composite unit cells with smaller lattice mismatch can be constructed (see SI Section S1: Tables S1-S6 and Figure S1 for details), but their cell sizes become too large for practical use, and improvements in quality are expected to be minimal.

**Results and Discussion**

**Effects of Lattice Strain on Graphene**

The fact that the two crystal systems are non-commensurate leads to lattice mismatch and applied compressive or tensile strain at the interface. This issue is encountered e.g. in epitaxial films and interfaces, which often have strong chemical bonding at the interfaces, and also in computational studies of any periodic composite system because of the need to
construct finite-size cells. Due to the greater geometric flexibility of graphene relative to rutile, the final lattice parameters are chosen to fit the rutile (110) component, forcing graphene to be deformed. This may change the electronic properties of graphene in such interfaces, compared to isolated graphene. Thus far, computational studies of the TiO$_2$-graphene interfaces have not explored the structural and electronic effects that this applied strain may have on the graphene component of the system.

The effect of strain was, however, explored in fundamental studies of pristine graphene. While some studies indicated that an applied tensile deformation of 1% to the graphene lattice was sufficient to introduce a band gap, further investigations instead showed that the observed band gap opening in graphene was due to the migration of the Dirac point (where the band structure of graphene moves from insulating to metallic) from its original position at the high symmetry k-point ‘K’, as a direct consequence of the change in lattice symmetry. It was found that the applied deformation required to introduce a band gap in graphene is at least 26.5% for uniaxial tensile strain (only in the zigzag direction); the gap can also be opened by anisotropic biaxial strain combining tension (11% in the zigzag direction) and compression (-20% in the armchair direction). Notably, these levels of strain are quite close to the predicted and measured failure strain of graphene, 20 – 25%. While these levels of strain are much higher than those encountered in our composite cell, we will set out to explore the effect of low levels of strain on the electronic properties of graphene.

In this work lattice deformation was applied to the orthorhombic graphene cell in the zigzag and armchair directions, up to ±6% strain in steps of 1% relative to the fully optimised cell. In addition, much larger strain values of up to ±30% (i.e. up to the predicted strains for gap opening and for graphene’s mechanical failure) in steps of 5% were also tested to determine the strain required to open a band gap in graphene. The fundamental band gaps (Figure 2 and Table S7) were obtained based on the band structures produced for each of the unstrained and strained cells (see examples in Figure 3 and in Figure S2 in
Figure 2: Effect of strain on the physical properties of graphene. Top row: change in the calculated band gap; middle row: total energy relative to the fully optimised orthorhombic graphene, bottom row: shift of the Fermi level compared to the unstrained graphene. Left column: strain is applied along the armchair direction: right column: strain is applied along the zigzag direction.

The band gap values show that the structure remains a conductor through most of the low values of strain tested. There is no significant change observed in the band structure for graphene under applied tensile or compressive uniaxial strain. The Dirac point remains observable up to ±6% applied strain (the amount of strain that we have assumed acceptable for commensurate cells) and as far as −20% − +25% strain. Consequently, the observed fundamental band gaps show very little variation from zero (close to or below the accuracy limit of 0.01 eV caused by the finite k-point sampling, see SI Section S2 for details), nor any discernible pattern, for all applied strains between −20% and +25% in both uniaxial
Figure 3: Band structures of orthorhombic graphene cells: optimised (a), 6% zigzag tensile strain (b), and 6% armchair tensile strain (c). Occupied bands are represented in blue, unoccupied bands are in red, and the dashed line represents the Fermi level. Slight changes in the band shapes and a migration of the Dirac point along the Γ-X line can be seen.

Figure 3: Band structures of orthorhombic graphene cells: optimised (a), 6% zigzag tensile strain (b), and 6% armchair tensile strain (c). Occupied bands are represented in blue, unoccupied bands are in red, and the dashed line represents the Fermi level. Slight changes in the band shapes and a migration of the Dirac point along the Γ-X line can be seen.

directions. Only at the highest tested level of strain, 30% stretching in the zigzag direction, the Dirac point disappears and a band gap can be observed, which agrees with literature observations.89,95,96

As an additional test of accuracy of our graphene electronic structure, the Fermi velocity \( v_F \) was calculated for the unstrained and +6% stretched (armchair and zigzag direction) graphene: the \( v_F \) values were \( 1.54 \times 10^6 \) m s\(^{-1} \), \( 1.57 \times 10^6 \) m s\(^{-1} \) and \( 1.30 \times 10^6 \) m s\(^{-1} \), respectively. These values are in good agreement with the experimentally measured range \((1.15 - 2.49) \times 10^6 \) m s\(^{-1} \) (where the variation depends on the substrate where graphene was deposited)\(^{101}\) and with theoretical values: \((0.85 - 0.9) \times 10^6 \) m s\(^{-1} \) (LDA calculations)\(^{101,102}\) and \((1.0 - 1.25) \times 10^6 \) m s\(^{-1} \) (GW calculations);\(^{102}\) the trend in our values of \( v_F \) is also in good agreement with recent calculations\(^{103}\) which reported a slight increase and a decrease upon stretching in the armchair and zigzag direction, respectively. These results give additional confirmation that our modelling of graphene band structure is reliable.

While there is no band gap opening in graphene observed at low levels of strain, there is however an increase in the total energy, which follows a roughly parabolic trend (Figure 2): very small changes (below 0.1 eV) for the first ±2% of applied strain and is relatively minor changes (below 0.5 eV) for the first ±6%, followed by a rapid increase. These changes in the total energy result in a shift of the energy levels and thus will result in a change in the work function of graphene in the composite: the change in the work function is small (within ±0.2
eV) for the first ±6% of applied strain, but becomes larger for hypothetical large applied strain (Figure 2 and Table S7). Any shift in band energies will therefore have a direct impact on where the valence band of graphene lies in relation to rutile (110), and at large strains it may affect the predicted transfer of charge across the interface.

In conclusion, we have demonstrated that the small applied strain on the graphene component in our composite system will not disrupt the semimetallic properties of graphene in the system, nor will it have a significant effect on its band positions.

**Binding Properties of the TiO$_2$/Graphene Interface**

To investigate the physical properties of the TiO$_2$/graphene composite system, the interlayer spacing, and interface interaction energies and binding energies were calculated using CP2K with the PBE + D method. For this work the interlayer spacing is determined as the vertical (z-axis) distance, in Ångströms, between the uppermost atomic layer of two-coordinated oxygen atoms of rutile (110) and the graphene layer. The interface interaction energy is defined as:

$$E_{int} = E_{tot} - E_{ru-opt} - E_{gr-opt} + E_{BSSE}$$  \hspace{1cm} (1)

where $E_{int}$ is the interaction energy, $E_{tot}$ is the computed total energy of the system, $E_{ru-opt}$ is the total energy of the optimised rutile (110) slab, $E_{gr-opt}$ is the total energy of the optimised graphene sheet, and $E_{BSSE}$ is the basis set superposition error correction. The interaction energy can be decomposed into the *deformation* energy $E_{def}$ (the energy change when deforming the TiO$_2$ and graphene components upon formation of the composite structure) and the *binding* energy $E_{bind}$ (the energy gain due to the binding of these deformed components, or, the interaction energy excluding the change due to deformation) defined as:

$$E_{bind} = E_{int} - E_{def}$$  \hspace{1cm} (2)
\[
E_{\text{def}} = (E_{\text{ru-def}} - E_{\text{ru-opt}}) + (E_{\text{gr-def}} - E_{\text{gr-opt}})
\]

where \(E_{\text{ru-def}}\) and \(E_{\text{gr-def}}\) are, respectively, the energies of the rutile (110) and graphene components in the geometry of the composite system. Interaction and binding energies and interlayer spacing for our system and a few reference systems are provided in Table S8. The interaction energies calculated in this work (−0.019 to −0.023 eV per carbon atom and −1.35 to −1.67 eV per cell) are very similar to the literature values for the same rutile (110)-graphene interface obtained using a different method (LDA+U). These weak interaction energies indicate physisorption. Dispersion is the principal mechanism of the interaction, e.g. in the system with the 9-layer TiO\(_2\) slab, dispersion contributes −3.13 eV to the binding energy of −3.24 eV. The alternative orientation of graphene above rutile, where the zigzag line of graphene is parallel to the A cell vector of rutile (110), results in very similar energies per carbon atom, confirming that interaction energies are very weakly dependent on the interfacial orientation, as expected for physisorption. Therefore the selected orientation of graphene above TiO\(_2\) is representative of the properties of the many possible random orientations which may occur in experimental TiO\(_2\)/graphene composites.

Comparing our interface interaction energies (scaled per carbon atom) to the literature values for the anatase (101)-graphene interface (−0.032 to −0.050 eV per carbon atom), the rutile (110)-based system is less strongly bound, probably because fewer atoms in the rutile (110) surface are close enough to graphene (only 2-coordinated surface oxygens). Comparing the rutile (110)/graphene composite to graphite, the composite’s interaction energies per carbon atom are half as small as computational and experimental values for the interlayer binding in graphite and multilayer graphene — this can be expected, since the TiO\(_2\)-graphene interface does not offer \(\pi\)-stacking such as found in graphite.

The deformation energies are 1.03 and 1.56 eV for the 6- and 9-atomic-layer TiO\(_2\) slabs, respectively. A large part of this is the deformation of graphene resulting mainly from the lattice mismatch (see the computational methods section). This gives an energy change due
to deformation of 0.68 and 0.83 eV/cell for the 3 and 2-layer composite systems respectively. The deformation of rutile (110) costs 0.22 and 0.89 eV in the 6- and 9-atomic-layer TiO2 slabs, respectively.

The difference between the 6-layer and 9-layer TiO₂ systems is related to the well-known oscillation of physical properties in odd- and even-layer rutile (110) slabs: for example, odd-layer rutile (110) slabs are found to have higher surface energies than even-layer slabs. The results of this work are in agreement with this pattern: since the 9-layer slab has a larger surface energy, it displays a larger energy gain due to the formation of the interface with graphene, especially obvious in the binding energies which do not include deformation.

Figure 4: One-dimensional potential energy surface (PES) plot of the rutile (110)/graphene composite. Insets show the alignment of graphene carbon atoms (teal) with the surface 2-coordinated oxygen atoms (blue) at several positions (maxima and minima) of the PES.

To study the effect of the alignment of graphene above the rutile (110) surface, the potential energy surface (PES) was sampled by moving the graphene sheet in both the A and B directions of the composite unit cell (defined in Figure 1), initially in steps of 0.6 Å in both directions and then additionally in steps of 0.2 Å in the A direction. The analysis showed very little variation in energy (0.03 eV) upon displacement along the B direction.
(graphene moving along the row of 2-coordinated oxygens of TiO$_2$), while the displacement along the A direction showed noticeable changes in energy. It can be seen in Figure 4 that the total energy increases as the carbon atoms in the graphene layer approach the 2-coordinated oxygen atoms in the rutile (110) surface layer, and is the most favourable when C–C bonds in the graphene layer rest over the top of these surface oxygen atoms (see insets in Figure 4). The energies vary by up to only 0.29 eV/cell. This very small variation suggests that there is no strongly preferred position of graphene above rutile (110). Diffusion along the B direction is essentially barrierless (0.03 eV) at room temperature. In the A direction, it is also easy to overcome the small barrier of 0.09 eV; the highest barrier of 0.29 eV results in the rate of approximately one movement every 10 ns (estimated using the Arrhenius equation with the prefactor of $10^{13}$ s$^{-1}$). Therefore, a variety of graphene/TiO$_2$ positions and orientations are likely to exist in experimental systems. Note, however, that this conclusion is true only for defect-free graphene; once oxygen functional groups are introduced to create graphene oxide, diffusion is likely to be impeded.

In conclusion, we have demonstrated that the interface between rutile (110) and graphene forms through a physisorption interaction, slightly weaker than the strength of interaction in multilayer graphene. The potential energy surface for this system is largely flat in shape, however, there exists a weak preference for aligning the surface 2-coordinated oxygen atoms with the mid-point of the carbon–carbon bonds in the graphene layer above.

**Electronic Properties of the Rutile (110)/Graphene Interface**

To analyse the possibility of charge transfer in the rutile (110)/graphene interface, we investigated the alignment of the electronic energy levels of TiO$_2$ and graphene in the composite system. Projected density of states (PDoS) spectra for the 6- and 9-atomic-layer rutile (110)/graphene composites and their corresponding isolated rutile (110) slabs have been calculated using the HSE06 hybrid functional in CRYSAL14 (see Figure 5 and Figure S3 in the SI; all DoS plots incorporate vacuum level correction, as stated in the Computational
Methods section).

Figure 5: PDoS spectra of the 9 atomic layer rutile (110) slab (bottom) and its composite with graphene (top). The projections shown are: carbon (red), surface site 5-coordinated titanium (dark blue), surface site 6-coordinated titanium (cyan), subsurface titanium positions: below surface Ti$_{5c}$ (green); below surface Ti$_{6C}$ (purple), 2-coordinated oxygen (orange). The total DoS is shown in black. The dashed lines represent the valence and conduction bands of the isolated rutile (110) slab and the Fermi-level of the composite.

The band gaps of isolated TiO$_2$ slabs are found to be 3.9 eV in the 6-layer system and 2.8 eV in the 9-layer system (band edges are shown with dashed lines in Figure 5 and Figure S3). This variation in the band gap values reflects the odd-even slabs’ oscillation of properties, characteristic of rutile (110): the band gaps are notably larger than the bulk value for even-layer slabs and smaller for odd-layer slabs. Overall, the band gaps found in this work are in good agreement with the value of 3.39 eV found for bulk rutile with the same HSE06 functional in Ref. and with the experimental values of 3.0 eV for the optical gap and $3.3 \pm 0.5$ eV fundamental band gap for rutile.

The graphs Figure 5 and Figure S3 show that both in isolated TiO$_2$ and in the composite
system the conduction band (CB) is primarily made up of titanium states, and the valence band (VB) of oxygen states, as is known from the literature on TiO\textsubscript{2} bulk and surfaces.\textsuperscript{80,81} In the 6 atomic layer rutile (110) systems the conduction band contains both the 5-coordinated Ti (Ti\textsubscript{5c}) and 6-coordinated Ti (Ti\textsubscript{6c}) surface states in roughly equal intensities (Figure S3). In the composite system containing the 9 atomic layer rutile (110) slab, the states localised on 5-coordinated titanium atoms and subsurface titanium atoms immediately below dominate in the low-energy part of the CB. The most prominent difference between the isolated rutile (110) slab and the composite is the shift of the surface 5-coordinated titanium atoms’ states (dark blue line in Figure 5) towards the low-energy part of the CB of the composite, which confirms electronic interaction between the TiO\textsubscript{2} surface and graphene.

![Figure 6: PDoS spectra of the 6 (top) and 9 (bottom) atomic layer rutile (110)/graphene composites. The projections shown are: Carbon (red), 5-coordinated titanium (dark blue), 6-coordinated titanium (cyan), subsurface titanium (green: below 5-coordinated surface site, purple: below 6-coordinated surface site), and 2-coordinated oxygen (orange). The dashed line represents the Fermi level, the solid black lines represent the valence and conduction band edges of the isolated rutile (110) slab.](image)

The high-resolution PDoS plots in Figure 6 show that both the upper part of the valence
band and the lowest part of the conduction band of the composite system (both located in the TiO$_2$ band gap region) are made up mostly of graphene states. Notably, the graphene-dominated conduction band edge is $\sim 0.8$ eV and $\sim 1.3$ eV, in composites with the 9- and 6-atomic-layer rutile (110) slabs respectively, below the Ti-dominated high-intensity states of the conduction band (which start between $-5.0$ and $-4.5$ eV). We observe that the unoccupied states of graphene lie well below the unoccupied states of TiO$_2$ which is in agreement with experimental work function and electron affinity values, which show graphene to have a larger work function (measured as 4.5 eV$^{108}$ or between 4.89 and 5.16 eV$^{109}$) compared to TiO$_2$ (work function of rutile (110) experimentally measured as 4.2 eV$^{110}$ electron affinity experimentally measured as $4.3 - 4.4$ eV$^{111,112}$ and calculated as 4.7 eV$^{112}$). 

Note that this alignment of Ti and carbon states is different from several recently published studies of TiO$_2$-graphene interfaces, where the graphene conduction band edge as usually found to lie near, just below, or just above the TiO$_2$ band edge.$^{111,114,115}$ There is, however, no agreement on the alignment of C- and Ti-based conduction band states in the published studies, and there are examples of C states being lower in energy than Ti states, similar to the results of this work, notably in graphene interfaces with anatase (001)$^{115}$ and rutile (110).$^{115}$ This difference is likely to be caused by differences in the electronic properties of anatase and rutile polymorphs of TiO$_2$ (indeed, the CB of anatase is believed to be $0.2 - 0.4$ eV below that of rutile$^{113,114}$). It is also likely that the TiO$_2$ band positions in the DFT+U calculations$^{111,114,115}$ are affected by the choice of the ‘U’ parameter which is applied to describe the on-site Coulomb interaction of Ti 3d electrons. We believe that hybrid functionals offer a less ambiguous description of band gaps and band positions. In particular, the HSE06 functional used in this work accurately predicts the band gaps, band positions and defect states in TiO$_2$.$^{113,115}$ This functional has also been successfully used to describe optical properties of carbon nanotubes,$^{116}$ band gaps of carbon nanoribbons$^{117}$ and workfunctions of graphene, carbon nanoribbons and nanotubes.$^{118,119}$ With this good description of the individual TiO$_2$ and nanocarbon components, it can be expected that this
functional’s description of the TiO\textsubscript{2}-graphene interface is also reliable.

This position of graphene-dominated states far below TiO\textsubscript{2} states rather than just below TiO\textsubscript{2} states has important implications for charge transfer in this composite system: it is strongly favourable for photoexcited electrons to decay to the bottom of the conduction band, \textit{i.e.} to these low-lying graphene-dominated states.

The high-resolution PDOS plots \textbf{[Figure 6]} show a clear qualitative difference between the composite systems involving 9-atomic-layer and 6-atomic layer TiO\textsubscript{2} slabs. In the 6-layer-based composite, only carbon-based states appear in the band gap of TiO\textsubscript{2}, suggesting very little electronic interaction between graphene and TiO\textsubscript{2}. By contrast, in the 9-layer-based composite, Ti-based states appear together with the carbon-based states near the bottom of the conduction band, in what would be the TiO\textsubscript{2} band gap. This points to electronic interaction between carbon and TiO\textsubscript{2} components, as these states are not present in the rutile component alone (see \textbf{Figure 5}). This mixture of titanium and carbon states in the conduction band is likely to affect the nature of charge transfer in this system. To investigate the origin of these Ti states, we plot the band structure and then explore the atomic orbitals which make up these bands.

The band structure of the 9 atomic layer composite is compared to the corresponding DoS spectrum in \textbf{Figure 7}. The band structure clearly shows that the Dirac point of graphene is preserved and can be seen close to the $\Gamma$ point, along the $\Gamma$–$Y$ line. The Fermi level lies slightly below the Dirac point, indicating hole doping of graphene; this is confirmed by the electron density difference plot (Figure S4 in the SI), which shows some electron transfer from graphene to TiO\textsubscript{2}. The amount of charge transferred has been evaluated as 0.68 electrons per cell (or 0.01 electrons per carbon atom), which is comparable to 0.02 electrons per carbon found for the similar system in Ref.\textsuperscript{41} The downshift of the Fermi level (0.42 eV) is slightly smaller than in the previously reported study of this interface using the DFT + U method (0.65 eV\textsuperscript{41}). Comparing the band structure of the composite system in \textbf{Figure 7} with the band structure of the isolated rutile slab and isolated graphene sheet (Figure S5), we can see
Figure 7: Band structure of the 9 atomic layer rutile (110)/graphene composite system, showing 10 occupied bands (shown in blue) and 10 unoccupied bands (in red). The PDoS spectrum of this interface is shown to the left, with the total DoS included in black, and guidelines relating parts of the DoS spectrum to the band structure. Additional annotations show the energies of possible electronic transitions and the composition of various regions of the band structure (assigned according to the analysis shown in Figure 8).

that the electronic structure of TiO$_2$ and graphene remain essentially intact in the composite system. Although the Dirac point has not been captured in our DoS plots (Figure 6 and S3), it is clearly present in the band structure. The apparent band gap in the DoS, similar to the small$^{[11,12,13]}$ or very small$^{[50]}$ band gaps observed in some of the previous studies of TiO$_2$/graphene interfaces, has likely been caused by the use of insufficiently dense $\mathbf{k}$-point grids, similar to the early studies of strained isolated graphene alone.$^{[8,9,11]}$ The absence of a band gap means that electrons can be easily promoted to the unoccupied graphene states. From these spectra it can also be seen that the thermodynamically favoured location of photoexcited electrons will be on graphene.
The question still remains about the origin of Ti-based states in the region corresponding to the band gap of pure TiO\textsubscript{2}. These states do not correspond to any special points in the conduction band (see Figure 7). The DoS plots in Figure 6 show that these states are localised on subsurface (bulk-like) Ti atoms of the 9 atomic layer rutile slab. The 6 atomic layer slab, which has no bulk-like Ti atoms, has no such gap states. This shows that subsurface Ti atoms are essential for strong electronic interaction between TiO\textsubscript{2} and graphene and that the 6 atomic layer slab, which has no subsurface atoms, is too small to model the rutile-graphene interface. The narrower band gap of the odd-layer rutile slab also brings the conduction band edge closer to the highest occupied band of graphene, facilitating the electronic interaction between graphene and TiO\textsubscript{2} (in agreement with the larger binding energy of graphene with the 9 atomic layer rutile slab). The localisation on subsurface Ti atoms is in qualitative agreement with the LDA+U study of Du \textit{et al.}\textsuperscript{41} which showed that the first two CB states are predominantly based on graphene and subsurface Ti atoms below surface Ti\textsubscript{5c}. This important role of the subsurface Ti atoms in the TiO\textsubscript{2} rutile (110)/graphene interaction is likely related to the tendency of excess electrons in rutile (110) slabs to localise at subsurface Ti sites.\textsuperscript{120,121} Since there is some charge transfer from graphene to TiO\textsubscript{2} in the ground state (as shown above), these subsurface Ti atoms are the most likely sites to accommodate this excess charge, and thus the presence of even one subsurface layer enhances the rutile (110)/graphene interlayer binding.

From these results one can see that, in order to correctly model the properties of this composite system, at least one subsurface layer of rutile (110) must be present. Thus the 9-layer rutile (110) slab is the smallest slab sufficient to describe this system, and we expect that thicker rutile (110) slabs will behave qualitatively similar.

To understand the origin of the Ti-based gap states, eigenvalues (atomic orbital (AO) coefficients) of several highest occupied and lowest unoccupied bands were analysed. Squares (complex conjugates) of AO coefficients $c_{i,j,k}c_{i,j,k}^*$ (where $i$ is the atom number, $j$ is the orbital (eigenstate), $k$ is the $k$-point) were calculated and summed over all Ti, all O and all C atoms,
to give the contributions of Ti, O and C to each eigenstate at each \( \mathbf{k} \)-point: \( \sum c^*_T_{i,j,k}, \sum c^*_O_{j,k} \) and \( \sum c^*_C_{j,k} \). The analysis of the AO coefficients at the \( \mathbf{k} \)-points along the band structure path (Figure 8) confirms that the highest occupied band (labelled “VBM”) as a whole consists mainly of carbon states. Similarly, the 3 highest energy VBs consist entirely of carbon states, and titanium and oxygen states begin to emerge at the VBM-4 and lower (energy -8.3 eV and below in Figure 7). The lowest unoccupied band (labelled “CBM”) around the \( \Gamma \)-point, and along most of the \( \Gamma-X \) and \( \Gamma-Y \) lines, consists mainly of carbon states, while at and around \( \mathbf{k} \)-points X, Y, and S it is predominantly titanium. These rutile titanium bands can be identified easily by their characteristically flat profiles – they are essentially the same as lowest-energy unoccupied bands of isolated rutile (also seen as intense peaks in the DoS, starting at \( \sim -5.0 \) eV, see Figure 5 and Figure 6).

The band lines in Figure 7 and Figure 8 look smooth and do not reflect the sharp Ti peaks seen near the bottom of the CB in the DoS. However, the band structure is plotted along special high-symmetry lines in the Brillouin zone (BZ), while the DoS is calculated by integrating over the whole BZ. To explain the DoS shape, we analysed atomic orbital coefficients of the highest occupied and two lowest unoccupied states across the full BZ. The contributions by atom type (\( \sum c^*_T_{i,j,k}, \sum c^*_O_{j,k} \) and \( \sum c^*_C_{j,k} \)) were calculated for VBM, CBM and CBM+1 on the \( 12 \times 12 \times 1 \) grid of \( \mathbf{k} \)-points covering the whole BZ (the same grid as used in the DOS calculations).

Figure 9 shows these AO contributions for the CBM and CBM+1, plotted on a 2D grid covering the irreducible part of the BZ of the composite. The sizes of circles in Figure 9 correspond to the magnitude of the species’ contribution to each of these bands at each \( \mathbf{k} \)-point. The VBM (results not shown) is predominantly (97 – 99%) composed of C states at all considered \( \mathbf{k} \)-points, in agreement with our DoS and band line analysis. The CBM is separated into two regions. Across most of the BZ (from -6.0 to -5.0 eV), this band is entirely localised on carbon atoms with negligible contributions from Ti and O atoms; however, the regions of the BZ immediately next to the X-S and Y-S lines (at \( > -5.0 \) eV) are
Figure 8: Energies of selected bands (VBM-1, VBM, CBM, CBM+1), plotted together with the sums of squared atomic orbital coefficients for all titanium, oxygen, and carbon species in the 9 atomic layer composite system. These data points cover all \( k \)-points in the path chosen for the band structure in Figure 7.

almost entirely localised on Ti atoms with very small contributions of O atoms. The second unoccupied band (labelled “CBM+1”) has the most interesting pattern of atomic orbitals’ contributions across the BZ: the regions next to the X-S and Y-S lines are again almost entirely localised on Ti atoms, the region around the \( \Gamma \) point is entirely localised on C atoms, while in the intermediate BZ region, as the electron energies increase, the main contributors change from C to Ti. Thus, Ti contributions appear at lower energies than in pure TiO\(_2\). Therefore, this second unoccupied band is not entirely graphitic and demonstrates electronic interaction between the carbon and TiO\(_2\) components of the composite. Interestingly, there
Figure 9: Sums of squared atomic orbital coefficients (shown as circles) for all titanium, oxygen, and carbon species in the 9 atomic layer composite system, plotted in the irreducible part of the Brillouin zone of the rutile (110)/graphene composite system. The areas of the circles correlate with the magnitude of each atomic species’ contribution to the eigenstate (CBM or CBM+1) at each k-point (blue circles for Ti, yellow for O, red for C). The variation of these bands’ energies across the BZ is shown with thin contour lines.

are no “mixed” states equally made up of C and Ti at any of the points in the BZ in this region; there is clear separation between C-dominated and Ti-dominated states.

Applying this analysis of atomic orbitals to the DoS plot in Figure 6 and Figure 7, it becomes clear that the carbon contributions in the low-energy region of the CB (−6.0 to −5.0 eV) come from both the first and the second unoccupied bands, while the titanium contributions come only from the second unoccupied band, at certain points in the BZ. The observation that Ti states contribute at some rather than all points in the BZ explains why the Ti states appear as spikes rather than as a smooth band in the DoS. This appearance of Ti states alongside C states in the graphene-like lower part of the CB is an indication of electronic interaction between graphene and rutile (110) - notably, interaction with subsurface (bulk-like) Ti atoms.

From this analysis of the electronic structure, and from the evidence in published research, it is now possible to infer more details about the mechanism of photosensitisation enhancement upon irradiation of this composite system. The combination of our DoS,
band structure, and atomic orbital coefficient analysis enable us to make predictions about the likely nature of photoexcitation transitions in the TiO$_2$-graphene system. We note that a calculation of transition dipole moments and electronic excitations would be necessary for a full description of photoexcitation processes. This is beyond the scope of the current work, however, a qualitative picture of photoexcitation can be obtained from our DoS and atomic orbital data. Our data suggest that the mechanism of photoexcitation will differ depending on the energy of a given incident photon. For a visible-region photon (2.5–1.5 eV, some possible transitions shown schematically by red and green arrows in Figure 7), electronic transitions must originate from a carbon state within graphene. The excited state reached by the transition may then be either carbon- or titanium-based depending upon the photon energy. Very low-energy photons can excite only carbon $\pi$ to $\pi^*$ electronic transitions (i.e. no charge transfer). Visible-light photons can span the band gap further away from the Γ point and nearer the points X and Y, where titanium states begin to appear in the unoccupied states. Then, these titanium states may accept the photoexcited electron, resulting in graphene $\rightarrow$ TiO$_2$ transition (although the intensity of this transition is likely to be lower than that of the graphene $\rightarrow$ graphene transition, because the charge transfer excitation has smaller transition matrix elements due to small overlap of the wavefunction).

Thus, the experimentally observed broadening of the absorption range of the TiO$_2$ composites\cite{22,24,30,32,37} is attributed to the presence of these mixed graphene and titanium states. Transfer of photoinduced electrons to TiO$_2$ creates an efficient photoreduction catalyst.\cite{16,20} Note however, that the lowest-energy unoccupied states are all graphene-based (both at the bottom of the conduction band and just above the Fermi level), therefore the thermodynamically favourable process is for the photoexcited electrons to eventually decay to these lowest-energy unoccupied carbon states. Thus, photoexcited charge transfer from graphene to TiO$_2$ is likely to be only a transient phenomenon (cf. a recent experimental study\cite{122} highlights the complex nature of recombination of hot electrons injected from graphene to TiO$_2$), unless photoexcited electrons and holes rapidly diffuse in TiO$_2$ or are used elsewhere,
for example, in photocatalytic reactions. Similarly, if an electron is supplied from elsewhere (e.g. using molecular sensitisers), it will most likely end up in these graphene-based lowest-occupied carbon states. Both processes make graphene the electron-rich part of the composite, so that it may act as an electron shuttle in complex photocatalyst architectures, as proposed by Kamat. It is also those electrons in the lowest-energy unoccupied carbon states which are then likely to recombine with holes in the valence band.

Photons in the ultraviolet range (\(> 3.0 \text{ eV}\)) are able to excite transitions that originate from deeper levels in the lower VBs, which are localised on TiO\(_2\). The accepting states are likely to be mixed graphene/titanium or purely titanium based, thus the overall direction of the charge transfer in this case is from TiO\(_2\) to graphene, as observed in many UV-Vis experiments.

In all cases that we have discussed, the final states reached by photoexcitations are likely to involve both carbon- and titanium-based states. The direct carbon \(\pi\) to \(\pi^*\) electronic excitations are likely to be more intense than charge-transfer carbon\(\rightarrow\)TiO\(_2\) excitations even if the energy of the excitation is the same. These carbon \(\pi\) to \(\pi^*\) excitations, however, can be followed by excited-state charge injection to same-energy titanium-based states, as observed by Manga et al. and described computationally by Long et al. Experimental data showing the visible-region photon absorption enhancement provided by graphene in this system support this model of a combination of direct (e.g. carbon \(\pi - \pi^*\)) and charge-transfer excitations.

**Conclusions**

In summary, we have performed a quantum chemical study with the aim to model the rutile (110)/graphene composite photocatalyst system, using 6 and 9 atomic layer rutile (110) slabs. The potential inaccuracy associated with the mismatch in lattice parameters between the rutile and graphene components in the system has been evaluated. Here it is shown that
small compressive and tensile strain on graphene from the mismatch results in only small increase in total energy and negligible opening of the band gap (up to 0.01 eV) in the case of mismatches of 6\% or fewer, and shows that the lattice mismatch of our chosen system (1.4-2.3 \%) is small enough to have no effect on the electronic properties of graphene. The interfacial interaction and binding energies have been calculated for both 6 and 9 atomic layer composites, which show that the interaction strength is noticeably greater for the 9 atomic layer system than the 6-atomic layer system. For the 9 atomic layer system specifically, the calculated interaction energy per carbon atom (-0.045 eV/atom) is comparable to that of graphite.

Separation of photoinduced charges is one of the most beneficial properties of TiO$_2$-graphene composite photocatalysts: thanks to this separation of charges, electron-hole recombination is greatly reduced, resulting in long-lived electrons and holes. We investigate the nature of charge separation in this composite by analysing the density of states, band structure and orbital composition of this material. We show that the lowest unoccupied states of these composites are dominated by graphene, therefore after relaxation (but before decaying to the valence band) photoexcited electrons are likely to end up in the graphene component. Our analysis of the electronic structure of the TiO$_2$-graphene composites elucidates how different wavelengths of photons are likely to result in different types of photoinduced charge separation. For example, visible light photons are likely to induce electron excitations from entirely carbon-based states (top of the VB) to both C- and Ti-based states (overall photoinduced electron transfer graphene $\rightarrow$ TiO$_2$), while UV photons may produce excitations from Ti-based states (deeper in the VB) again to both C- and Ti-based states (overall photoinduced electron transfer TiO$_2$ $\rightarrow$ graphene). Thus, photoexcitations with the different charge-transfer characters are possible, depending on the excitation wavelength. However, both types of photoexcitations produce charge-transfer states, thus creating electron-rich and hole-rich materials for photocatalytic reduction and oxidation.

The use of a hybrid DFT functional has demonstrated that correcting the unphysical
self-interaction energy present in pure DFT functionals is important for the accurate simulation of this composite’s electronic properties. The application of modern computational techniques and supercomputing resources in this research has shown that hybrid HF/DFT level calculations are possible on a large system such as this interface.

Finally, it should be noted that this work focussed entirely on composites formed by pristine graphene. As many experimental systems are synthesised from graphene oxide, the realistic composite may contain a number of oxygen functional groups, such as epoxy, hydroxyl and carboxyl, which may form bridges between graphene and titanium dioxide and have been suggested as an important contributor to electron transfer between TiO$_2$ and graphene. Therefore one of our future directions will be to investigate the difference between pristine graphene and graphene oxide in terms of the composition of occupied and unoccupied bands and the direction of charge transfer.

Supporting Information Available

The following files are available free of charge. Construction of commensurate unit cells; strain testing data; additional band structures of strained graphene; interaction energy data; density of states spectra; charge density difference images; band structures of isolated TiO$_2$ and graphene; an example of the input file used for the 9-atomic layer rutile (110)/graphene composite system.

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Notes
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References


(24) Cargnello, M.; Grzelczak, M.; Rodríguez-González, B.; Syrgiannis, Z.; Bakhmutsky, K.; La Parola, V.; Liz-Marzán, L. M.; Gorte, R. J.; Prato, M.; Fornasiero, P.


(33) Pastrana-Martínez, L. M.; Morales-Torres, S.; Likodimos, V.; Falaras, P.; Figueiredo, J. L.; Faria, J. L.; Silva, A. M. T. Role of Oxygen Functionalities on


(49) Qian, W.; Greaney, P. A.; Fowler, S.; Chiu, S.-K.; Goforth, A. M.; Jiao, J. Low-
Temperature Nitrogen Doping in Ammonia Solution for Production of N-Doped TiO$_2$-
Hybridized Graphene as a Highly Efficient Photocatalyst for Water Treatment. *ACS

(50) Ferrighi, L.; Fazio, G.; Di Valentin, C. Charge Carriers Separation at the

(51) Xu, L.; Huang, W.-Q.; Wang, L.-L.; Huang, G.-F. Interfacial Interactions of Semicon-
ductor with Graphene and Reduced Graphene Oxide: CeO$_2$ as a Case Study. *ACS

(52) Yang, Y.-C.; Xu, L.; Huang, W.-Q.; Luo, C.-Y.; Huang, G.-F.; Peng, P. Electronic
Structures and Photocatalytic Responses of SrTiO$_3$ (100) Surface Interfaced with
Graphene, Reduced Graphene Oxide, and Graphane: Surface Termination Effect. *J.

(53) Geng, W.; Liu, H.; Yao, X. Enhanced photocatalytic properties of titania-graphene
*15*, 6025–6033.

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(55) Favaro, M.; Agnoli, S.; Di Valentin, C.; Mattevi, C.; Cattelan, M.; Artiglia, L.; Magna-
nano, E.; Bondino, F.; Nappini, S.; Granozzi, G. TiO$_2$/Graphene Nanocomposites
from the Direct Reduction of Graphene Oxide by Metal Evaporation. *Carbon*

(56) Bukowski, B.; Deskins, N. A. The Interactions Between TiO$_2$ and Graphene with


(111) Butler, M. A.; Ginley, D. S. Prediction of Flatband Potentials at Semiconductor—...


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